



Technical Specification
Of
1.55 μ m MQW-DFB Laser Diode:
SLT1430 Series

1. General

SLT1430 Series are 1.55 μ m InGaAsP/InP MQW-DFB laser diodes fabricated by OMVPE entirely.

These diodes have low threshold current and high performance at high temperature.

A laser diode is mounted into a coaxial package integrated with an InGaAs monitor PD and a aspherical lens cap.

2. Package dimension and pin assignment

(See attached appendix)

3. Absolute maximum ratings (Tc=+25°C, unless otherwise noted.)

Parameter	Symbol	Ratings	Unit
Storage temperature	Tstg	-40~+100	°C
Operating case temperature	Top	-40~+85	°C
Peak optical output power	Po	20	mW
Forward current (LD)	IfL	150	mA
Reverse voltage (LD)	VrL	2	V
Reverse voltage (PD)	VrP	15	V
Reverse current (PD)	IrP	2	mA
Soldering temperature (<10sec.)	Stemp	260	°C

4. Electrical and optical characteristics (Po=5mW, Tc=+25°C, unless otherwise noted.)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Threshold current	Ith	CW	-	10	15	mA
		CW, Tc=-40~+85°C	-	-	50	
Optical output power	Po	CW, If=lth+20mA	3.0	5.0	-	mW
		CW, If=lth+20mA, Tc=-40~+85°C	2.0	-	-	
Operating voltage	Vf	CW, Tc=-40~+85°C	-	-	1.6	V
Central wavelength	λ_c	CW	1540	1550	1560	nm
		CW, Tc=-40~+85°C	1530	-	1570	
Side-mode suppression ratio	SMSR	CW, Tc=+25°C	30	35	-	dB
		CW, Tc=-40~+85°C	30	-	-	
Rise time	tr	lb=lth, 20-80%	-	-	0.15	nsec.
		lb=lth, 20-80%, Tc=-40~+85°C	-	-	0.25	
Fall time	tf	lb=lth, 80-20%	-	-	0.20	nsec.
		lb=lth, 80-20%, Tc=-40~+85°C	-	-	0.30	
Monitor current	Im	CW, VrP=5V	100	500	-	pA
		CW, VrP=5V, Tc=-40~+85°C	80	-	-	
Monitor dark current	Id	VrP=5V	-	-	10	nA
		VrP=5V, Tc=-40~+85°C	-	-	30	
Monitor capacitance	C	VrP=5V, f=1 MHz, Tc=-40~+85°C	-	-	10	pF

5. Ordering information

Part number	Pin assignment	Pin length
SLT1430	Type A	13.5±0.5mm
SLT1431	Type B	13.5±0.5mm
SLT1436	Type C	13.5±0.5mm

6. Precaution

- (1) Radiation emitted by laser devices can be dangerous to the eyes. Avoid eye or skin exposure to direct or scattered radiation.
- (2) The governmental approval is required to export this product to other countries. To dispose of this product, the appropriate procedure should be taken to prevent illegal exportation.
- (3) The laser diodes should be handled in the same manner as ordinary semiconductor devices to prevent the electro-static damages. For safe keeping and carrying, the modules should be packaged with ESD proof material. To assemble the modules on PCB, the workbench, the soldering iron and the human body should be grounded.
- (4) Please pay special attention to the atmosphere condition because the dew on the module may cause some electrical damages. :
- (5) Under such a strong vibration environment as in automobile, the performance and reliability are not guaranteed.

Appendix

Part No.: SLT143 □/□□□

(Customize code)

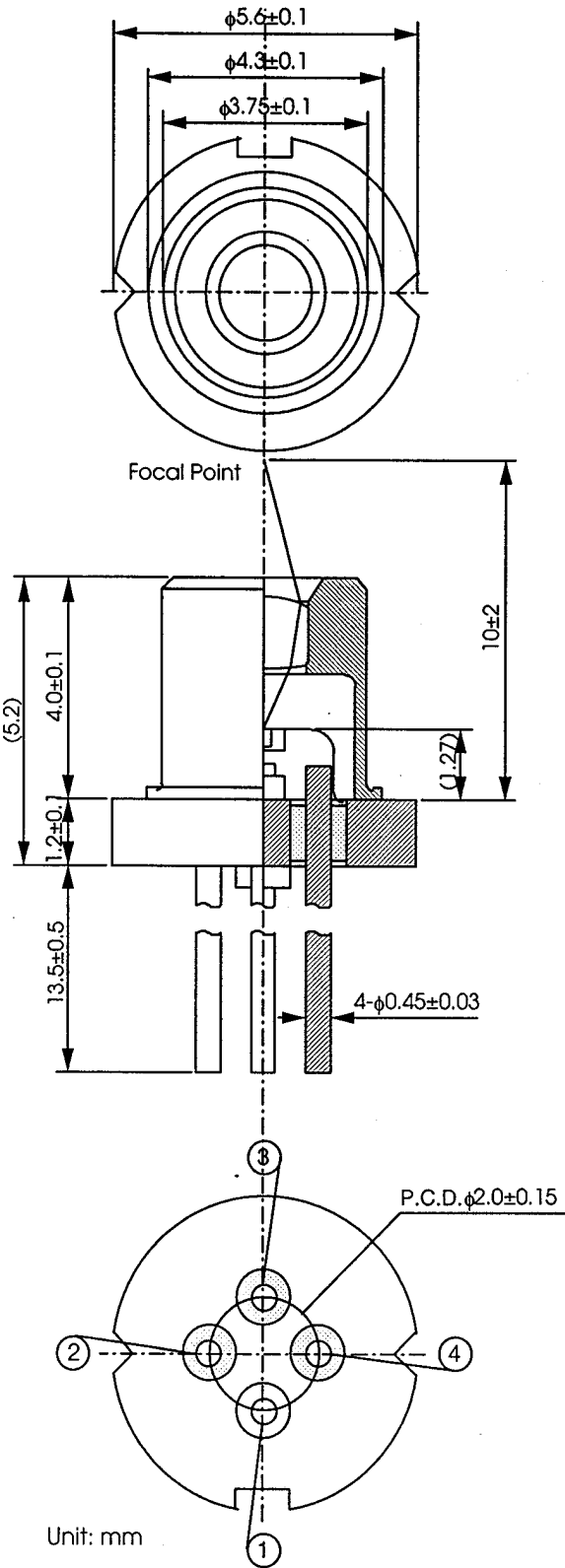
Code Pin assignment (Pin length (L))		
0	Type A	13.5±0.5
1	Type B	13.5±0.5
6	Type C	13.5±0.5

Pin No.	Pin function
1	LD anode (CASE)
2	PD cathode
3	PD cathode
4	PD anode

Pin No.	Pin function
1	LD anode (CASE)
2	PD anode
3	PD cathode
4	LD cathode

Pin No.	Pin function
1	LD anode (CASE)
2	PD anode
3	PD cathode
4	LD cathode

Pin Assignment



Sumitomo Electric Industries, Ltd.
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7. For More Information

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